

General Multilayer Ceramic Capacitors



MLCC is an electronic part that temporarily stores an electrical charge and the most prevalent type of capacitor today. New technologies have enabled the MLCC manufacturers to follow the trend dictated by smaller and smaller electronic devices such as Cellular telephones, Computers, DSC, DVC

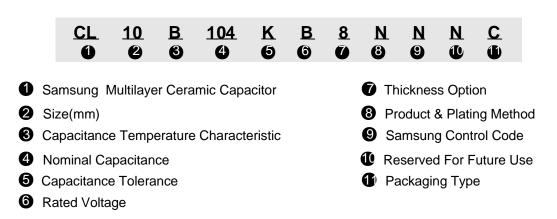
General Features

- Miniature Size
- Wide Capacitance and Voltage Range
- Tape & Reel for Surface Mount Assembly
- Low ESR

Applications

- General Electronic Circuit

Part Numbering



Samsung Multilayer Ceramic Capacitor

2 SIZE(mm)

Code	EIA CODE	Size(mm)
03	0201	0.6 × 0.3
05	0402	1.0 × 0.5
10	0603	1.6 × 0.8
21	0805	2.0 × 1.25
31	1206	3.2 × 1.6
32	1210	3.2 × 2.5
43	1812	4.5 × 3.2
55	2220	5.7 × 5.0



General Capacitors



Code	Temperature Characteristics				Temperature Range
С		COG	C	0 ± 30 (ppm/ $^{\circ}\mathrm{C}$)	
Р		P2H	P	-150 ± 60	
R		R2H	R△	-220±60	
S	Class	S2H	SA	-330±60	-55 ~ +125℃
Т		T2H	TΔ	-470±60	
U		U2J	UA	-750±60	
L		S2L	SA	+350 ~ -1000	
Α		X5R	X5R	±15%	-55 ~ +85℃
В	Class	X7R	X7R	±15%	-55 ~ +125℃
X		X6S	X6S	±22%	-55 ~ +105℃
F		Y5V	Y5V	+22 ~ -82%	-30 ~ +85℃

O CAPACITANCE TEMPERATURE CHARACTERISTIC

*** Temperature Characteristic**

Temperature Characteristics	Below 2.0pF	2.2 ~ 3.9pF	Above 4.0pF	Above 10pF
C∆	C0G	C0G	C0G	C0G
PΔ	-	P2J	P2H	P2H
RΔ	-	R2J	R2H	R2H
S∆	-	S2J	S2H	S2H
ТΔ	-	T2J	T2H	T2H
UΔ	-	U2J	U2J	U2J

O NOMINAL CAPACITANCE

Nominal capacitance is identified by 3 digits.

The first and second digits identify the first and second significant figures of the capacitance. The third digit identifies the multiplier. 'R' identifies a decimal point.

• Example

Code	Nominal Capacitance
1R5	1.5pF
103	10,000pF, 10nF, 0.01 ⊔ F
104	100,000pF, 100nF, 0.1 µ F



G CAPACITANCE TOLERANCE

Code	Tolerance	Nominal Capacitance
Α	±0.05pF	
В	±0.1pF	
С	\pm 0.25pF	Less than 10pF (Including 10pF)
D	± 0.5pF	
F	±1pF	
F	±1%	
G	±2%	
J	±5%	More than 10pE
К	±10%	More than 10pF
м	±20%	
Z	+80, -20%	

③ RATED VOLTAGE

Code	Rated Voltage	Code	Rated Voltage
R	4.0V	D	200 V
Q	6.3V	E	250V
Р	10V	G	500V
0	16V	н	630V
A	25V	I	1,000V
L	35V	J	2,000V
В	50V	к	3,000V
С	100 V		



7 THICKNESS OPTION

Size	Code	Thickness(T)	Size	Code	Thickness(T)
0201(0603)	3	0.30±0.03		F	1.25±0.20
0402(1005)	5	0.50±0.05		н	1.6±0.20
0603(1608)	8	0.80±0.10	1812(4532)	I	2.0±0.20
	Α	0.65±0.10		J	2.5±0.20
	С	0.85±0.10		L	3.2±0.30
0805(2012)	F	1.25±0.10		F	1.25±0.20
	Q	1.25±0.15	2220(5750)	н	1.6±0.20
	Y	1.25±0.20		I	2.0±0.20
	С	0.85±0.15		J	2.5±0.20
1206(3216)	F	1.25±0.15		L	3.2±0.30
	н	1.6±0.20			
	F	1.25±0.20			
	н	1.6±0.20			
1210(3225)	I	2.0±0.20			
	J	2.5±0.20			
	V	2.5±0.30			

③ PRODUCT & PLATING METHOD

Code	Electrode	Termination	Plating Type
Α	Pd	Ag	Sn_100%
N	Ni	Cu	Sn_100%
G	Cu	Cu	Sn_100%

③ SAMSUNG CONTROL CODE

Code Description of the code		Code	Description of the code
Α	Array (2-element)	N	Normal
В	Array (4-element)	Р	Automotive
С	High - Q	L	LICC



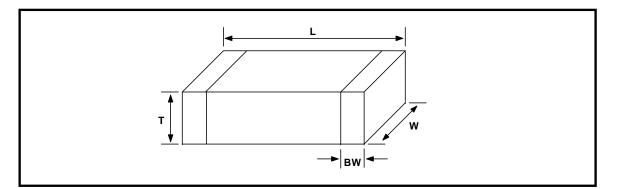
T RESERVED FOR FUTURE USE

Code	Description of the code
N	Reserved for future use

D PACKAGING TYPE

Code	Packaging Type	Code	Packaging Type
В	Bulk	F	Embossing 13" (10,000EA)
Р	Bulk Case	L	Paper 13" (15,000EA)
С	Paper 7"	0	Paper 10"
D	Paper 13" (10,000EA)	S	Embossing 10"
E	Embossing 7"		

APPEARANCE AND DIMENSION



CODE	EIA CODE	DIMENSION (mm)			
CODE		L	W	T (MAX)	BW
03	0201	$0.6~\pm~0.03$	$0.3~\pm~0.03$	0.33	$0.15~\pm~0.05$
05	0402	$1.0~\pm~0.05$	$0.5~\pm~0.05$	0.55	0.2 +0.15/-0.1
10	0603	1.6 ± 0.1	0.8 ± 0.1	0.9	0.3 ± 0.2
21	0805	2.0 ± 0.1	1.25 ± 0.1	1.35	0.5 +0.2/-0.3
	1000	3.2 ± 0.15	1.6 ± 0.15	1.40	0.5 +0.2/-0.3
31	1206	3.2 ± 0.2	1.6 ± 0.2	1.8	0.5 +0.3/-0.3
22	1010	$3.2~\pm~0.3$	$2.5~\pm~0.2$	2.7	0.6 ± 0.3
32	1210	3.2 ± 0.4	$2.5~\pm~0.3$	2.8	0.6 ± 0.3
43	1812	4.5 ± 0.4	3.2 ± 0.3	3.5	0.8 ± 0.3
55	2220	5.7 ± 0.4	5.0 ± 0.4	3.5	1.0 ± 0.3



SAMSUNG ELECTRO-MECHANICS

General Capacitors

NO	ITE	м	PER	FORMANCE	TEST	CONDITION		
1	Appea	rance	No Abnormal Exterior	Appearance	Through Microscope(×10))		
2	Insula Resist		10,000MΩ or 500MΩ-µF Rated Voltage is below 10,000MΩ or 100MΩ-µF	v 16V ;	Apply the Rated Voltage For 60 \sim 120 Sec.			
3	Withsta Volta		No Dielectric Breakdov Mechanical Breakdowr		Class I : 300% of the Rated Voltage for 1~5 sec. Class II :250% of the Rated Voltage for 1~5 sec. is applied with less than 50mA current			
	Capacita	Class I	Within the specifie	d tolerance	Capacitance ≤ 1,000 pF >1,000 pF	Frequency 1脸 ±10% 1脸 ±10%	Voltage 0.5 ~ 5 Vrms	
4	4 nce Class		Within the specifi	ed tolerance	Capacitance ≤ 10 μF >10 μF	Frequency 1雌 ±1 0% 120 Hz ±20%	Voltage 1.0±0.2Vrms 0.5±0.1Vrms	
5	Q	Class I	-	Q ≥ 1,000 : Q ≥ 400 +20C : Capacitance)	Capacitance ≤ 1,000 pF >1,000 pF	Frequency 1啦 ±10%	Voltage 0.5 ~ 5 Vrms	
6	Tan ∂	Class ∏	1. Characteristic : $A(x)$ Rated Voltage $\geq 25V$ 16V 10V 6.3V 2. Characteristic : $F(x)$ Rated Voltage 50V 35V 25V 16V 10V 6.3V	K5R), B(X7R), X(X6S) Spec 0.025 max 0.035 max 0.05 max 0.05 max/ 0.10max*1 Y5V) Spec 0.05 max, 0.07max*2 0.05 max/ 0.07 max 0.05 max/ 0.09max*4 0.09 max/ 0.125max*5 0.16max	Capacitance ≤ 10µF >10µF *1. 0201 C≥0.022uF, 0 0805 C≥4.7uF, 1206 1812 C≥47uF, 2220 All Low Profile Capa *2 0603 C≥0.47uF, 08 *3. 0402 C≥0.033uF, 06 All 0805, 1206 size, *4 1210 C>6.8uF *5 0402 C≥0.22uF *6 All 1812 size	6 C≥10uF, 1210 C≥100uF, citors (P.16). 05 C≥1uF 603 C>0.1uF) C≥22uF,	



SAMSUNG ELECTRO-MECHANICS

NO	ITE	M		MANCE		TEST CONDITION	
						Capacitance s	shall be measured by the steps
					Tana Orafficiant		following table.
			Characteri	istics	Temp. Coefficient (PPM/℃)	Step	- Temp.(℃)
			COG		0 ± 30	1	25 ± 2
			PH		-150 ± 60	2	Min. operating temp. ± 2
		Class	RH		-220 ± 60		
		I	SH		-330 ± 60	3	25 ± 2
			ТН		-470 ± 60	4	Max. operating temp \pm 2
				UL		-750 ± 120	5
			SL		+350 ~ -1000	(1) Class I	
	Tomporaturo						Coefficient shall be calculated from
7	Temperature Characteristics					the formula a	
,	of Capacitance					Temp, Coefficie	$nt = \frac{C2 - C1}{C1 \times \triangle T} \times 10^6 \text{ [ppm/°C]}$
							ance at step 3
						C2: Capacita	
			Characteristics Capacitance Chang with No Bias			∆T: 60℃(=8	
		Class	A(X5R	R)/	+ 450/		
		□ □	B(X7F	()	± 15%	(2) CLASS II	
			X(X65	S)	\pm 22%	Capacitance (Change shall be calculated from the
			F(Y5V	/)	+22% ~ -82%	formula as be	
						$\triangle C = \frac{C2}{C2}$	$\frac{C1}{1}$ × 100(%)
						· ·	ance at step 3 ance at step 2 or 4
							* Pressure for 10 ± 1 sec.
							201 case size.
						2009.1 101 0	
8	Adhesive	-	No Indication Of Peeling Shall Occur On The				
	of Termi	ination	Terminal Ele	Terminal Electrode.			500g.f
		A =	N			Bending limit	; 1mm
		Apperance	No mechar	nical dam	nage shall occur.	Test speed ;	1.0mm/SEC.
			Characte	eristics	Capacitance Change	Keep the test	board at the limit point in 5 sec.,
						Then measure	e capacitance.
					Within \pm 5% or \pm 0.		
			Class	s	5 pF whichever is		.20 .
					larger		<u>R=230</u>
9	Bending					50	
	Strength	Capacitance	1 1	A(X5R)/			
				B(X7R)/ X(X6S)	Within \pm 12.5%		
			-	7(703)		│	Bending limit
			Class II			45±1	45±1
				F(Y5V)	Within \pm 30%		
				/			
			-		1		



SAMSUNG ELECTRO-MECHANICS

NO	П	EM		PERF	ORMANCE		TEST CONDITION			
			More Thar	n 75% of th	ne terminal surface is to	Solder	Sn-3Ag-0.5	Cu 63Sn-37Pb		
				-	o metal part does not	Solder	245±5℃	235±5 ℃		
10	0.11	ar obility	come out	or dissolve		Temp.	240±0 U	230±3 C		
10	Solde	erability				Flux RMA Type				
			►			Dip Time	e 3±0.3 sec	. 5±0.5 sec.		
						Pre-heatin	g at 80~120	℃ for 10~30 sec.		
		Apperance	No mecha	anical dam	age shall occur.	Solder Temperature : 270±5°C				
			Charac	Characteristics Capacitance Change			10±1 sec.			
					Within ±2.5% or			fully immersed and		
			Clas	s I	$\pm 0.25\mathrm{pF}$ whichever is	preheated as below :				
		Capacitance			larger	STEP	TEMP.(℃)	TIME(SEC.)		
				A(X5R)/	Within ±7.5%	1	80~100	60		
			Class II	B(X7R)	Within ±15%	2	150~180	60		
	Resistance to			X(X6S) F	Within ±20%					
11	Soldering heat		Canacitan				•	bient condition for		
	concoming mouth	Q	Capacitar	ice ≥ 30 pF <30 pF	: Q≥ 1000 : Q≥ 400+20×C	<pre>specified time* before measurement * 24 ± 2 hours (Class I)</pre>				
		(Class I)		100 pr	(C: Capacitance)		nours (Class II			
		Tan δ								
		(Class Ⅱ)	Within the	e specified	initial value					
		Insulation			1.10.1 I					
		Resistance	Within the specified initial value							
		Withstanding Voltage	Within the specified initial value							
		Appearance	No mecha	anical dam	age shall occur.					
			Charact	teristics	Capacitance Change					
					Within ±2.5% or		itor shall be su	-		
			Clas	s I	$\pm 0.25 pF$ whichever is		-	a total amplitude of y from 10Hz to 55Hz		
		Capacitance			larger		to 10Hz In 1 m	-		
			0	A(X5R)/ B(X7R)	Within ±5%					
12	Vibration		Class	X(X6S)	Within ±10%	Repeat this	s for 2hours ea	ch in 3 mutually		
	Test			F(Y5V)	Within ±20%	perpendicu	lar directions			
		Q			J					
		(Class I)	Within the	e specified	initial value					
		Tan ∂	Within the	o sposific d	initial value					
		(Class Ⅱ)		- specilied	inniai value					
		Insulation Resistance	Within the	Within the specified initial value						
		10000100								





NO	ITE	м		PERFO	RMANCE	TEST CONDITION		
		Appearance	No mechanic	al damage shal		Temperature : 40±2 °C		
				cteristics	Capacitance Change	Relative humidity : 90~95 %RH		
						Duration time : $500 + 12/-0$ hr.		
			Cla	ss I	Within ±5.0% or ±0.5p ^F			
					whichever is larger	Leave the capacitor in ambient		
		Capacitance		A(X5R)/		condition for specified time* before		
			Class	B(X7R)/	Within ±12.5%	measurement.		
			П	X(X6S)		CLASS I : 24±2 Hr.		
				F(Y5V)	Within ±30%	$CLASSII : 24\pm 2$ Hr.		
		Q	Capacitance	\geq 30pF : Q \geq 3	350			
	Humidity	CLASSI	10≤ Capaci	tance <30 pF : Q	\ge 275 + 2.5×C			
13	(Steady	CLASSI	Capacitance	< 10pF : Q≥ 2	200 + 10×C (C: Capacitance)			
	State)		1. Characteri	stic : A(X5R),	2. Characteristic : F(Y5V)			
				B(X7R)				
			0.05max (16)	/ and over)	0.075max (25V and over)			
		Tan ∂	0.075max (10	DV)	0.1max (16V, C<1.0µF)			
		CLASS II	0.075max		0.125max(16V, C \ge 1.0 μ F)			
			(6.3V excep	t Table 1)	0.15max (10V)			
			0.125max*		0.195max (6.3V)			
			(refer to Tab	le 1)				
		Insulation				-		
		Resistance	1,000 MΩ or	50MΩ•µF whichev	rer is smaller.			
		Appearance	No mechanic	al damage shal	l occur.	Applied Voltage : rated voltage		
			Chara	cteristics	Capacitance Change	Temperature : 40±2 °C		
					Within ±5.0% or ±0.5pF	Humidity : :90~95%RH		
			Cla	ss I	whichever is larger	Duration Time : 500 +12/-0 Hr. Charge/Discharge Current : 50 ^{mA} max.		
						Charge/Discharge Current . 50m/ max.		
				A(X5R)/	Within ±12.5%	Perform the initial measurement according to		
		Capacitance		B(X7R)/	Within ±12.5%	Note1.		
				X(X6S)	Within ±30%	-		
			Class II		Within ±30%			
				F(Y5V)	Within ±30%	Perform the final measurement according to Note2.		
	Moisture	Q	Capacitance	≥30pF : Q≥ 2	00			
14	Resistance	(Class I)			0 + 10/3×C (C: Capacitance)			
			1. Characteri	stic : A(X5R),	2. Characteristic : F(Y5V)	-		
				B(X7R)				
			0.05max (16)	/ and over)	0.075max (25V and over)			
			0.075max (10	DV)	0.1max (16V, C<1.0μF)			
		T = >	0.075max		0.125max(16V, C≥ 1.0µ ^F)			
		Tan ∂	(6.3V excep	t Table 1)	0.15max (10V)			
		(Class Ⅱ)	0.125max*	,	0.195max (6.3V)			
			(refer to Tal	ble 1)				
			X(X6S) 0.11r	nax (6.3V and b	lelow)			
		Insulation Resistance	500 MΩ or 25	5MΩ•μF whichever	is smaller.			





NO	ITE	м		PER	FORMANCE		TEST CONDIT	ION	
		Appearance	No mechanio	cal damage	shall occur.		oltage : 200%* of the ire : max. operating t	-	
			Charact	eristics	Capacitance Change		ime : 1000 +48/-0 H		
				-	Within ±3% or ±0.3 pF,	Charge/Dis	Charge/Discharge Current : 50mA max.		
			Class	; 1	Whichever is larger	* refer to			
		Capacitance		A(X5R)/ B(X7R)	Within ±12.5%	voltage	* refer to table(3) : 150%/100% of the rated voltage Perform the initial measurement according to		
			Class II	X(X6S)	Within ±25%	Perform th			
	$\begin{array}{c c} F(Y5V) \\ \hline \\ Q \\ (Class I) \\ \end{array} \begin{array}{c} Capacitance \geq 30 pF \\ 10 \leq Capacitance < 30 \\ \end{array}$				Within ±30%	Note1 for	Note1 for Class II		
				F(Y5V)	Within ±30%				
			Capacitance	≥ 30 pF : C	Q ≥ 350		e fact measurement	according to	
			F : Q ≥ 275 + 2.5×C	Note2.	e final measurement	according to			
	18.1	(Class I)	Capacitance	< 10pF :Q	\geq 200 +10×C (C: Capacitance)				
15	High		1. Characteri	istic: A(X5R	R), 2. Characteristic : F(Y5V)				
15	Temperature Resistance			B(X7R))				
	Resistance		0.05max		0.075max				
			(16V and o		(25V and over)				
			0.075max (1	nax 0.125max(16V, C≥1.0µF)					
		Tan ∂	0.075max						
		(Class Ⅱ)	0.125max*	n Table T)	0.15max (10V) 0.195max (6.3V)				
			(refer to Ta	hle 1)	0.135118X (0.5V)				
			X(X6S) 0.11	max (6.3V a	nd below)				
		Insulation Resistance	1,000 MΩ or	50MΩ•µF whic	chever is smaller.				
		Appearance	No mechanio	al damage	shall occur.		r shall be subjecte	d to 5 cycles.	
			Charact	eristics	Capacitance Change	Condition	for 1 cycle :		
			Class	• T	Within ±2.5% or ±0.25 pF	Step	Temp.(℃)	Time(min.)	
				, 1	Whichever is larger	_ 1	Min. operating	30	
		Capacitance		A(X5R)/	Within ±7.5%		temp.+0/-3		
			Class	B(X7R)/	VVIIIII1 ±1.576	2	25	2~3	
16	Temperature		П	X(X6S)	6S) Within ±15%		Max. operating	30	
	Cycle			_	temp.+3/-0				
	Q Within the specified initial value		al value	4	25	2~3			
	(Class					Leave th	e capacitor in amb	ient condition	
		Tan ∂	Within the s	pecified initia	al value	· ·	fied time* before n	neasurement	
		(Class Ⅱ)					hours (Class I)		
		Insulation	Within the s	necified initia	al value	24 ± 2	24 ± 2 hours (Class II)		
		Resistance							



SAMSUNG ELECTRO-MECHANICS

RELIABILTY TEST CONDITION

		Reco	ommended Sold	ering Method		
		Size	Temperature		Cond	dition
		inch (mm)	Characteristic	Capacitance	Flow	Reflow
		0201 (0603)	_	-	-	0
		0402 (1005)				
			Class I	-	0	0
		0603 (1608)	Class II	C < 1 µF	0	0
				$C \geq 1 \mu F$	-	0
	Recommended Soldering Method		Class I	-	0	0
18		0805 (2012)	Class II	C < 4.7µF	0	0
	By Size & Capacitance			$C \geq 4.7 \mu F$	-	0
	-,		Array	-	-	0
			Class I	-	0	0
		1206 (3216)	Class II	C < 10 μ F	0	0
		1200 (3210)		$C \geq 10 \mu F$	-	0
			Array	-	-	0
		1210 (3225)				0
		1808 (4520)	_	_	_	0
		1812 (4532)		-	-	0
		2220 (5750)				0

Note1. Initial Measurement For Class $\ensuremath{\mathbbm I}$

Perform the heat treatment at $150\degree$ +0/- $10\degree$ for 1 hour. Then Leave the capacitor in ambient condition for 48 ± 4 hours before measurement.

Note2. Latter Measurement

1. CLASS ${\rm I}$

Leave the capacitor in ambient condition for $24{\pm}2$ hours before measurement

Then perform the measurement.

2. Class ${\rm I\hspace{-0.2em}I}$

Perform the heat treatment at 150° +0/- 10° for 1 hour. Then Leave the capacitor in ambient condition for 48 ± 4 hours before measurement.

*Table1.

Tan ∂	0.125max*		High Tem	perature Resistar
	0201 C \geq 0.022 μ F		⊿C (Y5V)	± 30%
	0402 C \geq 0.22 μ F			0402 C \geq 0.47
	0603 C \geq 2.2 μ F			0603 C \geq 2.2 μ
Class II	0805 C \geq 4.7 μ F		а т	0805 C \geq 4.7
A(X5R),	1206 C \geq 10.0 μ F		Class II	1206 C \ge 10.0
B(X7R)	$\begin{array}{rl} 1210 \ C &\geq 22.0\mu\mathrm{F} \\ \\ 1812 \ C &\geq 47.0\mu\mathrm{F} \end{array}$	F(Y5V)	1210 C ≥22.0	
B(XIII)			1812 C ≥47.0	
	2220 C \geq 100.0 μ F			$2220 C \geq 100$
	All Low Profile			
	Capacitors (P.16).			

*T	ab	le2	2.

*Table3.

erature Resistance test		High Temperature Resi	stance test
± 30%	Applied	100% of the rated	150% of the rated
0402 C \geq 0.47 μ F	Voltage	voltage	voltage
0603 C \geq 2.2 μ F		0201 C \geq 0.1 μ F	0201 C \geq 0.022 μ F
0805 C \geq 4.7 μ F		0402 C ≥ 1.0μF	0402 C \geq 0.47 μ F
1206 C \geq 10.0 μ F		0603 C \geq 4.7 μ F	0603 C \geq 2.2 μ F
1210 C \geq 22.0 μ F	A(X5R),	0805 C \geq 22.0 μ F	0805 C \geq 4.7 μ F
1812 C \geq 47.0 μ F	B(X7R),	1206 C ≥47.0µF	1206 C \geq 10.0 μ F
2220 C \geq 100.0 μ F	X(X6S), F(Y5V)	1210 C ≥ 100.0 <i>µ</i> F	1210 C \geq 22.0 μ F
	F(TOV)	All Low Profile	1812 C \geq 47.0 μF
		Capacitors (P.16).	2220 C \geq 100.0 μF

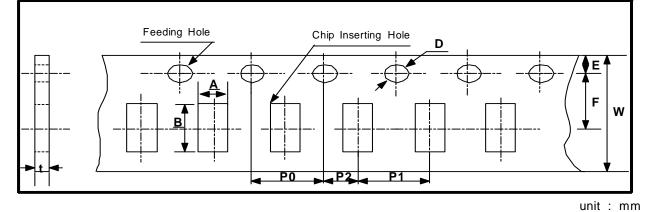
Note3. All Size In Reliability Test Condition Section is "inch"



SAMSUNG ELECTRO-MECHANICS

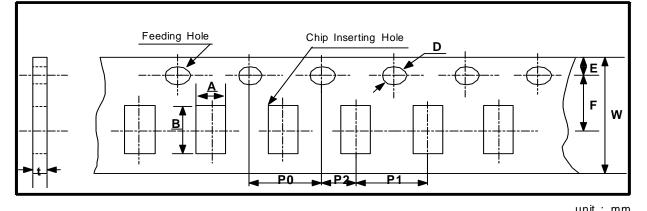
PACKAGING

CARDBOARD PAPER TAPE (4mm)



Symbol Α В w F Ε **P1** Ρ2 **P0** D t Туре D 0603 (1608) 1.1 1.9 i ±0.2 ±0.2 m е 0805 (2012) 1.6 2.4 8.0 3.5 1.75 4.0 2.0 4.0 Φ1.5 1.1 n ±0.2 ±0.2 ±0.3 ±0.05 ±0.1 ±0.1 ±0.05 ±0.1 +0.1/-0 Below s i 2.0 3.6 1206 (3216) ο ±0.2 ±0.2 n

• CARDBOARD PAPER TAPE (2mm)



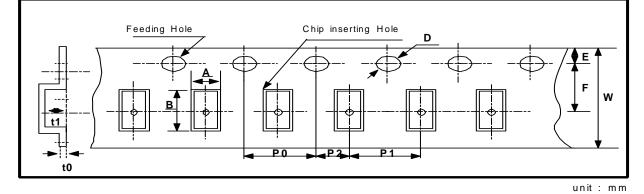
S	ymbol Type	А	В	w	F	Е	P1	P2	P0	D	nit:mm t
D i m e	0201 (0603)	0.38 ±0.03	0.68 ±0.03	8.0	3.5	1.75	2.0	2.0	4.0	Ф1.5	0.37 ±0.03
e n s i o n	0402 (1005)	0.62 ±0.04	1.12 ±0.04	±0.3	±0.05	±0.1	±0.05	±0.05	±0.1	+0.1/-0.03	0.6 ±0.05



SAMSUNG ELECTRO-MECHANICS

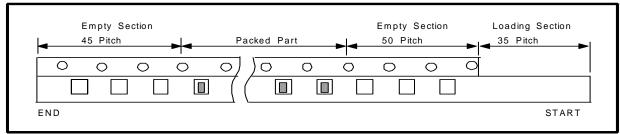
PACKAGING

EMBOSSED PLASTIC TAPE



	vm bol ype	Α	В	w	F	E	P1	P 2	P 0	D	t1	t0
	0805 (2012)	1.45 ±0.2	2.3 ±0.2									
Di	1206 (3216)	1.9 ±0.2	3.5 ±0.2	8.0 ±0.3	3.5 ±0.05		4.0 ±0.1				2.5 max	
m e	1210 (3225)	2.9 ±0.2	3.7 ±0.2			1.75		2.0	4.0	Ф1.5 +0.1/-0		0.6
n s i	1808 (4520)	2.3 ±0.2	4.9 ±0.2			±0.1		±0.05	±0.1	+0.17-0		Below
o n	1812 (4532)	3.6 ±0.2	4.9 ±0.2	12.0 ±0.3	5.60 ±0.05		8.0 ±0.1				3.8 max	
	2220 (5750)	5.5 ±0.2	6.2 ±0.2									

TAPING SIZE



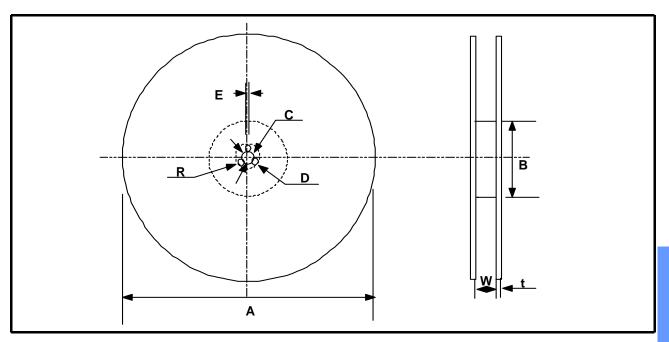
Туре	Symbol	Size	Cardboard Paper Tape	Symbol	Size	Embossed Plastic Tape
		0201(0603)	10,000	-	All Size ≤3216 1210(3225),1808(4520) (t≤1.6mm)	2,000
7" Reel	С	0402(1005)	10,000	E	1210(3225)(t≥2.0mm)	1,000
		OTHERS	4,000		1808(4520)(t≥2.0mm)	1,000
10" Reel	0	-	10,000	-	-	-
	D	0402(1005)	50,000		All Size ≤3216 1210(3225),1808(4520) (t<1.6mm)	10,000
		OTHERS	10,000		$1210(3225)(1.6 \le t < 2.0 \text{ mm})$ $1206(3216)(1.6 \le t)$	8,000
13" Reel		0603(1608)	10,000 or 15,000	F	1210(3225),1808(4520) (t \geq 2.0mm)	4,000
	L	0805(2012) (t≤0.85mm)	15,000 or 10,000(Option)		1812(4532)(t≤2.0mm)	4,000
		1206(3216) (t≤0.85mm)	10,000		1812(4532)(t>2.0mm) 5750(2220)	2,000





PACKAGING

• REEL DIMENSION



unit : mm

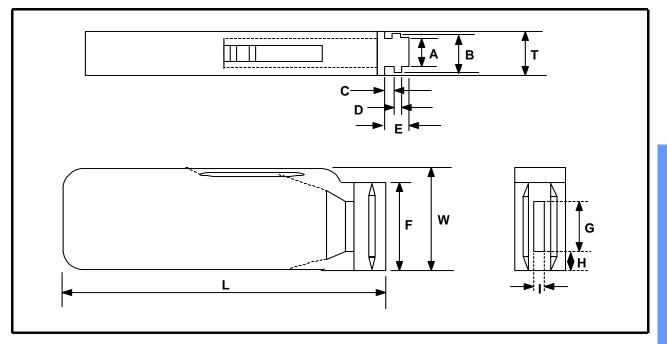
Symbol	Α	В	С	D	E	W	t	R
7" Reel	¢180+0/ -3	¢60+1/ -3		05 1 0 5		0 1 4 5	1.2±0.2	4.0
13" Reel	\$330±2.0	ф80 + 1/ -3	¢13±0.3	25±0.5	2.0±0.5	9±1.5	2.2±0.2	1.0

General Capacitors



BULK CASE PACKAGING

- Bulk case packaging can reduce the stock space and transportation costs.
- The bulk feeding system can increase the productivity.
- It can eliminate the components loss.



General Capacitors

unit : mm

Symbol	Α	В	Т	С	D	E
Dimension	6.8±0.1	8.8±0.1	12±0.1	1.5+0.1/-0	2+0/-0.1	3.0+0.2/-0

Symbol	F	W	G	Н	L	I
Dimension	31.5+0.2/-0	36+0/-0.2	19±0.35	7±0.35	110±0.7	5±0.35

• QUANTITY OF BULK CASE PACKAGING

unit : pcs

Ci-c	0402(1005)	00.02/40.00)	0805(2012)		
Size		0603(1608)	T=0.65mm	T=0.85mm	
Quantity	50,000	10,000 or 15,000	10,000	5,000 or 10,000	

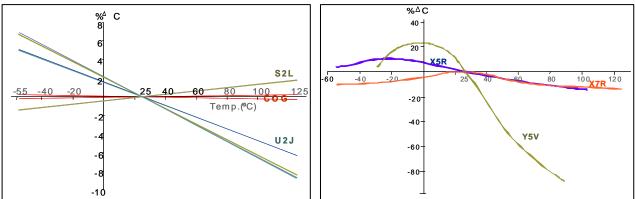


SAMSUNG Electro-Mechanics

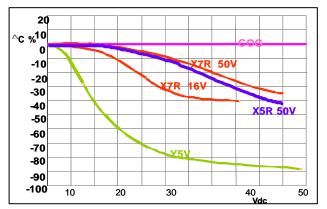
APPLICATION MANUAL

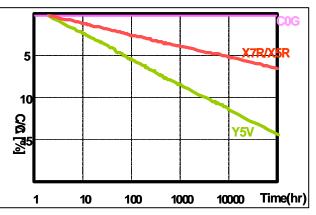
ELECTRICAL CHARACTERISTICS

► CAPACITANCE - TEMPERATURE CHARACTERISTICS

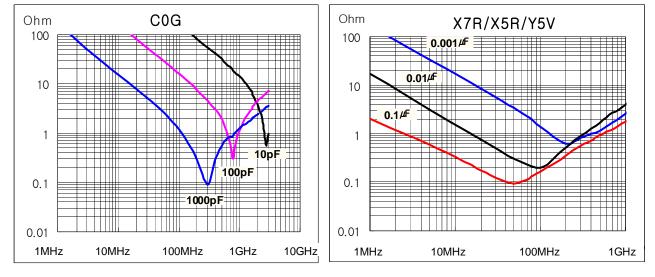


► CAPACITANCE - DC VOLTAGE CHARACTERISTICS ► CAPACITANCE CHANGE - AGING





▶ IMPEDANCE - FREQUENCY CHARACTERISTICS





STORAGE CONDITION

Storage Environment

The electrical characteristics of MLCCs were degraded by the environment of high temperature or humidity. Therefore, the MLCCs shall be stored in the ambient temperature and the relative humidity of less than 40 $^{\circ}$ and 70%, respectively.

Guaranteed storage period is within 6 months from the outgoing date of delivery.

Corrosive Gases

Since the solderability of the end termination in MLCC was degraded by a chemical atmosphere such as chlorine, acid or sulfide gases, MLCCs must be avoid from these gases.

Temperature Fluctuations

Since dew condensation may occur by the differences in temperature when the MLCCs are taken out of storage, it is important to maintain the temperature-controlled environment.

DESIGN OF LAND PATTERN

When designing printed circuit boards, the shape and size of the lands must allow for the proper amount of solder on the capacitor.

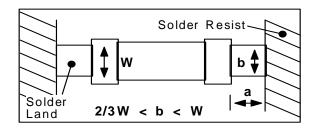
The amount of solder at the end terminations has a direct effect on the crack.

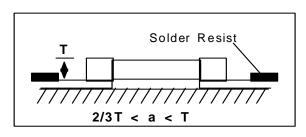
The crack in MLCC will be easily occurred by the tensile stress which was due to too much amount

of solder. In contrast, if too little solder is applied, the termination strength will be insufficiently.

Use the following illustrations as guidelines for proper land design.

Recommendation of Land Shape and Size.







ADHESIVES

When flow soldering the MLCCs, apply the adhesive in accordance with the following conditions.

Requirements for Adhesives

They must have enough adhesion, so that, the chips will not fall off or move during the handling of the circuit board.

They must maintain their adhesive strength when exposed to soldering temperature.

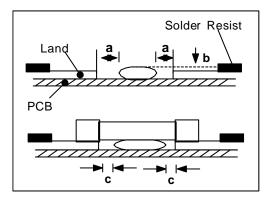
They should not spread or run when applied to the circuit board.

They should harden quickly. They should not corrode the circuit board or chip material.

They should be a good insulator. They should be non-toxic, and not produce harmful gases, nor be harmful when touched.

Application Method

It is important to use the proper amount of adhesive. Too little and much adhesive will cause poor adhesion and overflow into the land, respectively.



		unit : mm
Туре	21	31
а	0.2 min	0.2 min
b	70~100 µm	70~100 µm
С	> 0	> 0

Adhesive hardening Characteristics

To prevent oxidation of the terminations, the adhesive must harden at $160\,^\circ$ C or less, within 2 minutes or less.

MOUNTING

Mounting Head Pressure

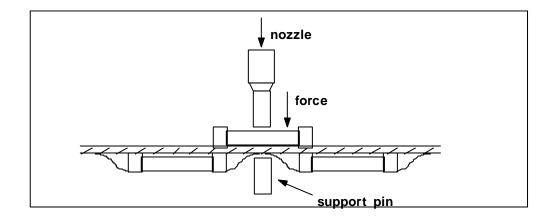
Excessive pressure will cause crack to MLCCs. The pressure of nozzle will be 300g maximum during mounting.



Bending Stress

When double-sided circuit boards are used, MLCCs first are mounted and soldered onto one side of the board. When the MLCCs are mounted onto the other side,

it is important to support the board as shown in the illustration. If the circuit board is not supported, the crack occur to the ready-installed MLCCs by the bending stress.



Manual Soldering

Manual soldering can pose a great risk of creating thermal cracks in chip capacitors. The hot soldering iron tip comes into direct contact with the end terminations, and operator's carelessness may cause the tip of the soldering iron to come into direct contact with the ceramic body of the capacitor.

Therefore the soldering iron must be handled carefully, and close attention must be paid to the selection of the soldering iron tip and to temperature control of the tip.

Amount of Solder

Too much Solder	Cracks tend to occur due to large stress
Not enough Solder	Weak holding force may cause bad connections or detaching of the capacitor
Good	



Cooling

Natural cooling using air is recommended. If the chips are dipped into solvent for cleaning, the temperature difference(\triangle T) must be less than 100 °C

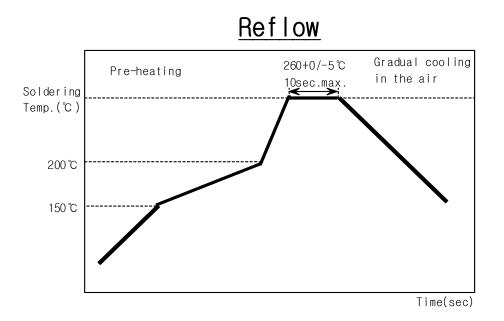
Cleaning

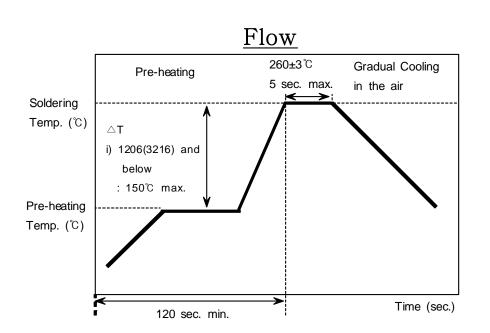
If rosin flux is used, cleaning usually is unnecessary. When strongly activated flux is used, chlorine in the flux may dissolve into some types of cleaning fluids, thereby affecting the chip capacitors. This means that the cleaning fluid must be carefully selected, and should always be new.

▶ Notes for Separating Multiple, Shared PC Boards.

A multi-PC board is separated into many individual circuit boards after soldering has been completed. If the board is bent or distorted at the time of separation, cracks may occur in the chip capacitors. Carefully choose a separation method that minimizes the bending often circuit board.

Recommended Soldering Profile





The Inside Edge

Soldering Iron

Variation of Temp.	Soldering	Pre-heating	Soldering	Cooling
	Temp (°C)	Time (Sec)	Time(Sec)	Time(Sec)
∆T≤130	300±10℃max	≥ 60	≤ 4	-

Condition of Iron facilities			
Wattage	Tip Diameter	Soldering Time	
20W Max	3mm Max	4 Sec Max	

* Caution - Iron Tip Should Not Contact With Ceramic Body Directly.

SAMSUNG ELECTRO-MECHANICS

SAMSUNG



单击下面可查看定价,库存,交付和生命周期等信息

>>Samsung Electro-Mechanics(三星电机)

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